# **NCE N-Channel Super Trench Power MOSFET**

#### **Description**

The NCEP3065QU uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{\text{DS(ON)}}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

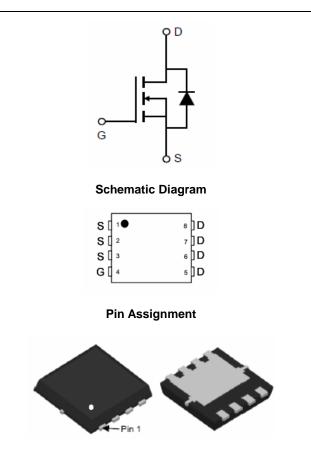
#### **General Features**

- $V_{DS} = 30V, I_D = 65A$   $R_{DS(ON)} = 1.9 m\Omega$  (typical) @  $V_{GS} = 10V$  $R_{DS(ON)} = 3.0 m\Omega$  (typical) @  $V_{GS} = 4.5V$
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 150 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

#### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED! 100% ΔVds TESTED!



**Bottom View** 

# **Package Marking and Ordering Information**

<b>Device Marking</b>	Device	Device Package	Reel Size	Tape width	Quantity
NCEP3065QU	NCEP3065QU	DFN3.3X3.3-8L	-	-	-

**Top View** 

#### Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	30	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	65	А
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100℃)	45.5	Α
Pulsed Drain Current	I <sub>DM</sub>	260	Α
Maximum Power Dissipation	P <sub>D</sub>	55	W
Derating factor		0.44	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	500	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}$



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# **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	$R_{\theta JC}$	2.3	°C/W
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Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	30		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.0	1.5	2.0	V
Durain Course On Chata Desintance	В	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	1.9	2.3	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A	-	3.0	3.6	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A		60	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\\ 45\\\\ 0\\	-	2100	-	PF
Output Capacitance	Coss	$V_{DS}$ =15V, $V_{GS}$ =0V, F=1.0MHz	-	773	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0WIn2	-	15.5	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	7.5	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =15 $V$ , $I_D$ =20 $A$	-	4.0	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =1.6 $\Omega$	-	37	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	7.5	-	nS
Total Gate Charge	Qg	V -45VI -20A	-	34.8	-	nC
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =15V,I <sub>D</sub> =20A,	-	6.2		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	5.1		nC
Drain-Source Diode Characteristics	<u>.                                      </u>		-		-	
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	65	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C$ , $I_F = I_S$	-	14	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	21	-	nC

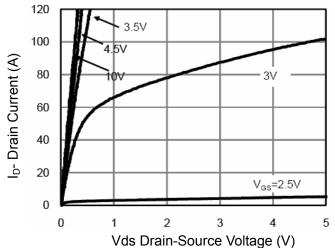
#### Notes:

- ${\it 1. Repetitive Rating: Pulse width \ limited \ by \ maximum \ junction \ temperature.}$
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,V\_DD=20V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$

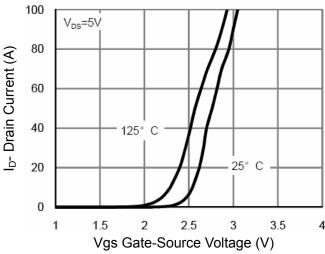
**Pb Free Product** 



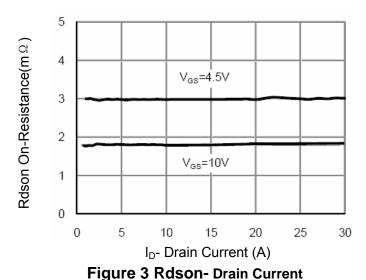
# **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 



1.8

90

1.6

V<sub>GS</sub>=10V

I<sub>D</sub>=20A

1.2

V<sub>GS</sub>=4.5V

I<sub>D</sub>=20A

1.3

V<sub>GS</sub>=4.5V

I<sub>D</sub>=20A

T<sub>J</sub>-Junction Temperature(°C)

**Figure 4 Rdson-Junction Temperature** 

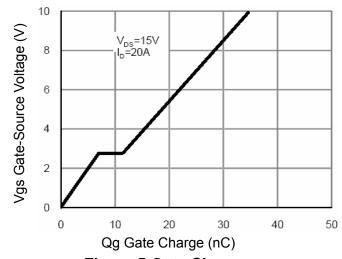


Figure 5 Gate Charge

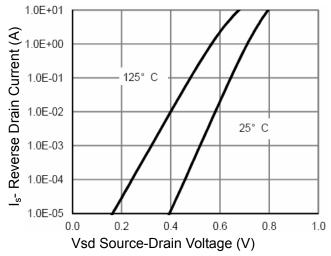


Figure 6 Source- Drain Diode Forward

# NCEP3065QU

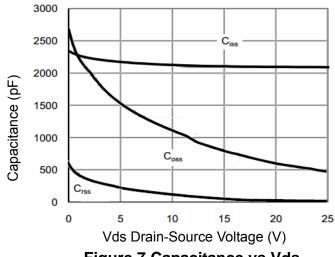


Figure 7 Capacitance vs Vds

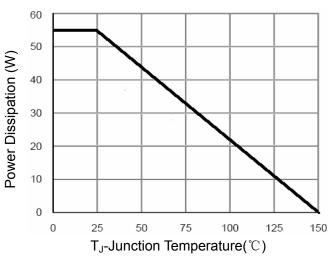
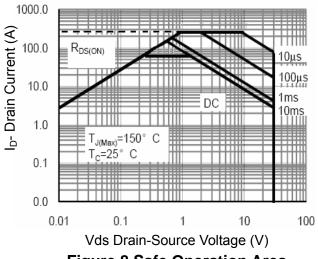


Figure 9 Power De-rating



**Figure 8 Safe Operation Area** 

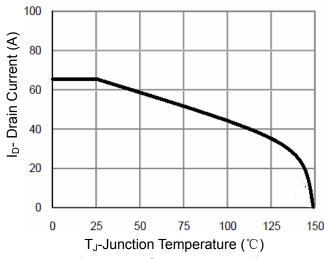


Figure 10 Current De-rating

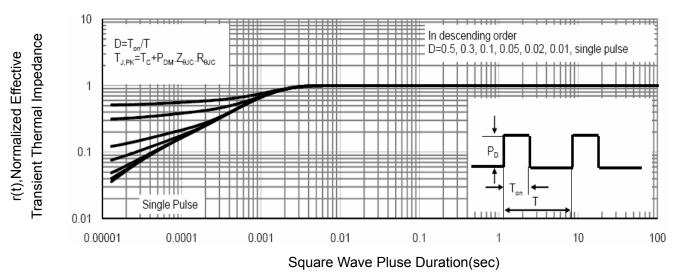
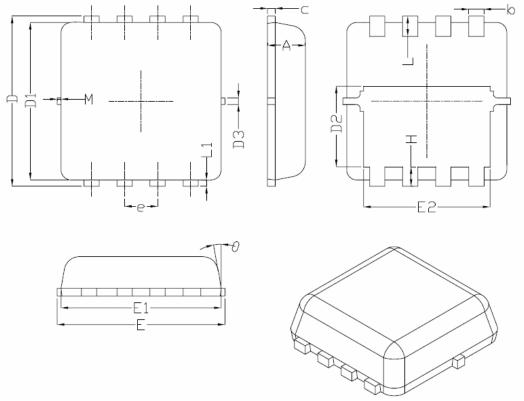


Figure 11 Normalized Maximum Transient Thermal Impedance

# **DFN3.3X3.3-8L Package Information**



Cumbal	Dimensions In Millimeters				
Symbol	Min.	Nom.	Max.		
A	0.70	0.75	0.80		
b	0.25	0.30	0.35		
С	0.10	0.15	0.25		
D	3.25	3.35	3.45		
D1	3.00	3.10	3.20		
D2	1.48	1.58	1.68		
D3	-	0.13	-		
E	3.20	3.30	3.40		
E1	3.00	3.15	3.20		
E2	2.39	2.49	2.59		
е					
Н	0.30	0.39	0.50		
L	0.30	0.40	0.50		
L1	-	0.13	-		
M	*	*	0.15		
θ		10°	12 <sup>°</sup>		



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